International Rectifier

MBR7535 MBR7545

SCHOTTKY RECTIFIER

70 Amp



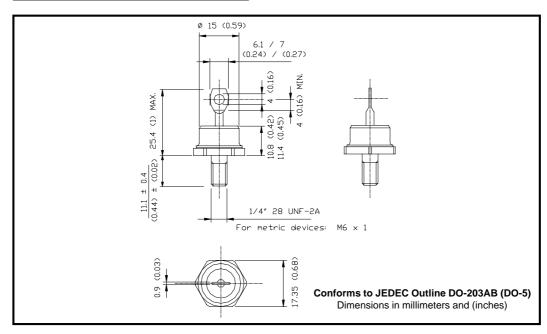
Major Ratings and Characteristics

Characteristics	MBR75	Units
I _{F(AV)} Rectangular waveform	70	А
V _{RRM}	35/45	V
I _{FSM} @ 60Hz	1000	Α
V _F @ 60 Apk, T _J = 125°C	0.60	V
T _J	-65 to 150	°C

Description/ Features

The MBR75.. Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150° C junction temperature. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- \bullet 150° C $\rm T_{\rm J}$ operation
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Hermetic packaging



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Voltage Ratings

Part number	MBR7535	MBR7545
V _R Max. DC Reverse Voltage (V)		
V _{RWM} Max. Working Peak Reverse Voltage (V)	35	45

Absolute Maximum Ratings

	Parameters	MBR75	Units	Conditions		
I _{F(AV)}	Max. Average Forward Current	70	Α	@ T _C =90°C, rectangular wave form		
I _{ESM}	Max. Peak One Cycle Non-Repetitive	9000	Α	5µs Sine or 3µs Rect. pulse	Following any rated	
	Surge Current	1000	_ ^	Surge applied at rated load condition	load condition and with rated V _{RRM}	
				halfwavesinglephase60Hz	applied	

Electrical Specifications

	Parameters	MBR75	Units	Conditions	
V_{FM}	Max. Forward Voltage Drop(1)	0.60	V	@ 60A	T, = 125 °C
		0.90	V	@ 220A	. js s
I _{RM}	Max. Instantaneus Reverse Current (1)	150	mA	T _J = 125 °C	Rated DC voltage
C _T	Max. Junction Capacitance	4000	pF	$V_R = 5V_{DC}$, (test signal range 100Khz to 1Mhz) 25°C	
L _s	Typical Series Inductance	7.5	nΗ	Measured from top of terminal to mounting plane	
dv/dt		10000	V/ µs		

⁽¹⁾ Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications

	<u> </u>				
	Parameters		MBR75	Units	Conditions
T_J	Max. Junction Temperature R	ange	-65 to 150	°C	
T _{stg}	Max. Storage Temperature Ra	ange	-65 to 150	°C	
R _{thJC}	Max. Thermal Resistance Jun to Case	ction	0.83	°C/W	DCoperation
R _{thCS}	Typical Thermal Resistance, C to Heatsink	Case	0.25	°C/W	Mounting surface, smooth and greased
wt	Approximate Weight		15 (0.53)	g(oz.)	
Т	MountingTorque	Min.	23 (20)	Kg-cm	
		Max.	46 (40)	(lbf-in)	
	Case Style		DO-203AB	(DO-5)	JEDEC

^{*} For Additional Informations and Graphs, Please See the 75HQ Series

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Data and specifications subject to change without notice.
This product has been designed for Industrial Level.
Qualification Standards can be found on IR's Web site.



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